

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

TK20J60U

• FEATURES

- Low drain-source on-resistance: Ros(ON) ≤ 190mΩ
- · Easy to control Gate switching
- · Enhancement mode: Vth = 3 to 5V (VDS = 10 V, ID=1mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

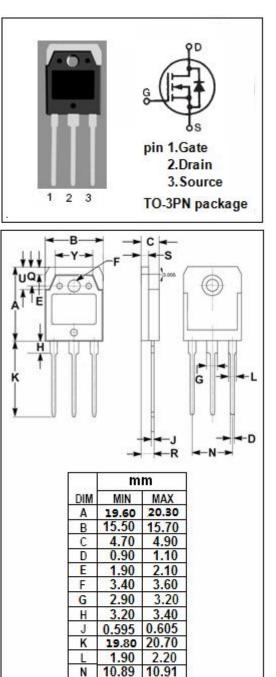
DESCRITION

Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C) SYMBOL PARAMETER VALUE				
STWIDOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V_{GS}	Gate-Source Voltage ±30			
ID	Drain Current-Continuous 20			
I _{DM}	Drain Current-Single Pulsed 40		A	
P _D	Total Dissipation @Tc=25°C	tion @T _c =25℃ 190		
Tj	Max. Operating Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55~150	ĉ	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.658	°C/W



isc website: www.iscsemi.cn

isc & iscsemi is registered trademark

Q

R

s

V

4.90

3.35

5.90

1.995

5.10

3.45

2.100

6.20

9.90 | 10.10

1



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ELECTRICAL CHARACTERISTICS

$T_{\texttt{C}}\text{=}25^{\circ}\!\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	600			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =1mA	3		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =10A			190	mΩ
lgss	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V			100	μA
VSDF	Diode forward voltage	I _{DR} =20 A, V _{GS} = 0 V			1.7	V

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